

PATENT & TRADEMARK OFFICE  
MAR 18 2002  
JC41

**COPY OF PAPERS  
ORIGINALLY FILED**

RECEIVED  
PATENT  
SQAR100ZP

TECH CENTER 2800

Please type a plus sign (+) inside this box.

Substitute for form 1449A/PTO

## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet

9

9

Application Number

**Complete if Known**

09/592349

Filing Date

June 12, 2000

**First Named Inventor**

Peatman et al.

Group Art Unit

2814

Examiner Name \_\_\_\_\_

D. Wille

Attorney Docket Number

SC11100ZP

## U. S. PATENT DOCUMENTS

[illegible]

## FOREIGN PATENT DOCUMENTS

[illegible]Examiner  
Signature

Douglas A. Little

Date  
Considered

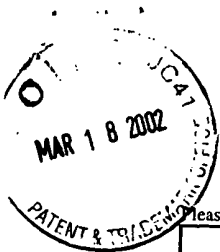
15 Feb 03

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup> Unique citation designation number. <sup>2</sup> See Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to place a check mark here if English Language Translation is attached.

COPY OF PAPERS  
ORIGINALLY FILED

PATENT  
SC11100ZP



Please type a plus sign (+) inside this box.

Substitute for form 1449A/PTO		<b>Complete if Known</b>			
		Application Number	09/592349		
<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (use as many sheets as necessary)		Filing Date	June 12, 2000		
		First Named Inventor	Peatman et al.		
		Group Art Unit	2814		
		Examiner Name	D. Wille		
Sheet		of		Attorney Docket Number	SC11100ZP

<b>OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS</b>			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
		BOISSENOT, P. et al., "A 0.4-UM Gate-Length AlGaAs/GaAs P-Channel HIGFET with 127-mS/mm Transconductance at 77 K", IEEE Electron Device Letters, IEEE Inc., vol. 11, no. 7, July 1, 1990, pp. 282-284.	

Examiner Signature		Date Considered	
-----------------------	--	--------------------	--

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup> Unique citation designation number. <sup>2</sup> Applicant is to place a check mark here if English Language Translation is attached.

RECEIVED

MAR 22 2002



